



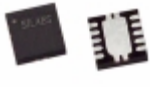




	<h2>SI3459DV-T1-E3</h2>
	<p>Hersteller-Teilenummer: SI3459DV-T1-E3</p> <p>Hersteller / Marke: Vishay / Siliconix</p> <p>Teil der Beschreibung: MOSFET P-CH 60V 2.2A 6-TSOP</p> <p>Datenblätter:  SI3459DV-T1-E3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 71457 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SI3459DV-T1-E3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET P-CH 60V 2.2A 6-TSOP
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	71457 pcs Stock
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	SOT-23-6 Thin, TSOT-23-6
Supplier Device-Gehäuse	6-TSOP
Verlustleistung (max)	2W (Ta)
Typ FET	P-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	60V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	2.2A (Tc)
Rds On (Max) @ Id, Vgs	220 mOhm @ 2.2A, 10V
VGS (th) (Max) @ Id	1V @ 250µA (Min)
Gate Charge (Qg) (Max) @ Vgs	14nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	-
Verpackung	Tape & Reel (TR)










































SI3459DV-T1-E3 ist neu im Original, Suche SI3459DV-T1-E3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI3459DV-T1-E3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI3459DV-T1-E3: Info@Y-IC.com

Sie können auch interessiert sein:

 SI3459BDY-T1-E3 VISHAY SI3459BDY-T1-E3 VISHAY	 SI3459SMART24-KIT Energy Micro (Silicon Labs) EVAL KIT SI3459/3483 POE CTLR	 SI3460-E02-GM Energy Micro (Silicon Labs) IC POWER MANAGEMENT CTLR 11VQFN	 SI3460-E02-GMR Energy Micro (Silicon Labs) IC POWER MANAGEMENT CTLR 11VQFN
 SI3459DV-T1-GE3 VISHAY SI3459DV-T1-GE3 VISHAY	 SI3459DV-T1-E3 Electro-Films (EFI) / Vishay MOSFET P-CH 60V 2.2A 6- TSOP	 SI3459BDV-T1-GE3 Electro-Films (EFI) / Vishay MOSFET P-CH 60V 2.9A 6- TSOP	 SI3459BDV-T1-GE3 Vishay / Siliconix MOSFET P-CH 60V 2.9A 6- TSOP

heiße Teile

Mehr

 SI3457BDV-T1-E3	 SI3457BDV-T1-GE3	 SI3457BDV-T1-GE3	 SI3457CDV-T1-E3	 SI3457CDV-T1-E3
 SI3457CDV-T1-GE3	 SI3457CDV-T1-GE3	 SI3457DV	 SI3457DV	 SI3457DV-T1
 SI3457DV-T1-E3	 SI3457DV-T1-GE3	 SI3457DV-T1-E3	 SI3458BDV-T1-E3	 SI3458BDV-T1-E3
 D SI3458BDV-T1-GE3	 SI3458BDV-T1-GE3	 SI3458DV-T1-E3	 SI3458DV-T1-E3	 SI3458DV-T1-GE3
 SI3459BDV-T1-E	 SI3459BDV-T1-E3	 SI3459BDV-T1-E3	 SI3459BDV-T1-GE3	 SI3459BDV-T1-GE3
 SI3459DV-T1-E3	 SI3459DV-T1-GE3	 D SI3460-E02-GMR	 SI3460-E03-GMR	 SI3460BDV-T1-E3
 SI3460BDV-T1-E3	 D SI3460BDV-T1-GE3	 SI3460BDV-T1-GE3	 SI3460DDV	 SI3460DDV-T1-GE3
 SI3460DDV-T1-GE3	 SI3460DV	 SI3460DV-T1	 SI3460DV-T1-E3	 SI3460DV-T1-E3
 SI3460DV-T1-GE3	 SI3460DV-T1-GE3	 SI3461DV-T1-E3	 D SI3461DVT1-GE3	 SI3464DV
 SI3464DV-T1-GE3	 SI3464DV-T1-GE3	 SI3465DV-T1-E3	 SI3465DV-T1-E3	 SI3465DV-T1-GE3

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